TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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- Supply Voltage Range . . . 1.8 V to 3.6 V
- Rail-to-Rail Input/Output
- High Bandwidth . . . 8 MHz
- High Slew Rate . . . 4.8 V/μs
- V_{ICR} Exceeds Rails . . . -0.2 V to V_{DD}+ 0.2
- Supply Current . . . 650 μA/Channel
- Input Noise Voltage . . . 9 nV/√Hz at 10 kHz
- Specified Temperature Range:
 0°C to 70°C... Commercial Grade
 -40°C to 125°C... Industrial Grade
- Ultrasmall Packaging
- Universal Operational Amplifier EVM

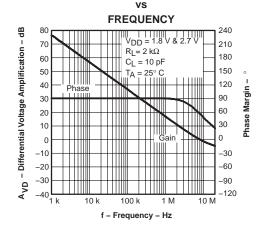
description

The TLV278x single supply operational amplifiers provide rail-to-rail input and output capability. The TLV278x takes the minimum operating supply voltage down to 1.8 V over the extended industrial temperature range (–40°C to 125°C) while adding

Operational Amplifier



DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE



the rail-to-rail output swing feature. The TLV278x also provides 8 MHz bandwidth from only 650 μ A of supply current. The maximum recommended supply voltage is 3.6 V, which allows the devices to be operated from (\pm 1.8 V supplies down to \pm 0.9 V) two rechargeable cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications.

All members are available in PDIP, SOIC, and the newer, smaller SOT-23 (singles), MSOP (duals), and TSSOP (quads).

FAMILY PACKAGE TABLE

DEVICE	V _{DD} [V]	V _{IO} [μV]	I _{DD} /ch [μΑ]	I _{IB} [pA]	GBW [MHz]	SLEW RATE [V/μs]	V _{n, 1 <u>kH</u>z [nV/√Hz]}	I _O [mA]	SHUTDOWN	RAIL-TO- RAIL
TLV278x(A)	1.8-3.6	250	650	2.5	8	5	18	10	Υ	I/O
TLV276x(A)	1.8-3.6	550	20	3	0.5	0.23	95	5	Υ	I/O
TLV246x(A)	2.7-6	150	550	1300	6.4	1.6	11	25	Υ	I/O
TLV247x(A)	2.7–6	250	600	2.5	2.8	1.5	15	20	Υ	I/O
TLV244x(A)	2.7–10	300	750	1	1.81	1.4	16	2	_	0
TLV277x(A)	2.5-5.5	360	1000	2	5.1	10.5	17	6	Y	0



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TLV2780 and TLV2781 AVAILABLE OPTIONS(1)

			PACKAGED DEVICES						
TA	V _{IO} max AT 25°C	SMALL OUTLINE	SOT-23	PLASTIC DIP					
	A1 23 C	(D)†	(DBV)‡	SYMBOL	(P)				
0°C to 70°C	3000 μV	TLV2780CD TLV2781CD	TLV2780CDBV TLV2781CDBV	VASC VATC					
-40°C to 125°C	3000 μV	TLV2780ID TLV2781ID	TLV2780IDBV TLV2781IDBV	VASI VATI	TLV2780IP TLV2781IP				
-40 0 10 125 0	2000 μV	TLV2780AID TLV2781AID	_ _	_					

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2780CDR).

TLV2782 and TLV2783 AVAILABLE OPTIONS(1)

			PACKAGED DEVICES								
TA	V _{IO} max AT 25°C	SMALL		MSOP							
		OUTLINE† (D)	(DGK)†	SYMBOL	(DGS)†	SYMBOL	DIP (N)	DIP (P)			
0°C to 70°C	3000 μV	TLV2782CD TLV2783CD	TLV2782CDGK —	xxTIADL —	— TLV2783CDGS	— xxTIADN	_ _	_ _			
40°C to 425°C	3000 μV	TLV2782ID TLV2783ID	TLV2782IDGK —	xxTIADM —	— TLV2783IDGS	— xxTIADO	— TLV2783IN	TLV2782IP —			
-40°C to 125°C	2000 μV	TLV2782AID TLV2783AID	_ _	_ _	_ _		_ _	_ _			

This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2782CDR).

TLV2784 and TLV2785 AVAILABLE OPTIONS(1)

	.,	PACKAGED DEVICES							
T _A	V _{IO} max AT 25°C	SMALL OUTLINE (D)	PLASTIC DIP (N)	TSSOP† (PW)					
0°C to 70°C	3000 μV	TLV2784CD TLV2785CD	_ _	TLV2784CPW TLV2785CPW					
-40°C to 125°C	3000 μV	TLV2784ID TLV2785ID	TLV2784IN TLV2785IN	TLV2784IPW TLV2785IPW					
-40 C to 125 C	2000 μV	TLV2784AID TLV2785AID		TLV2784AIPW TLV2785AIPW					

[†] This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2784CDR).

1. For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

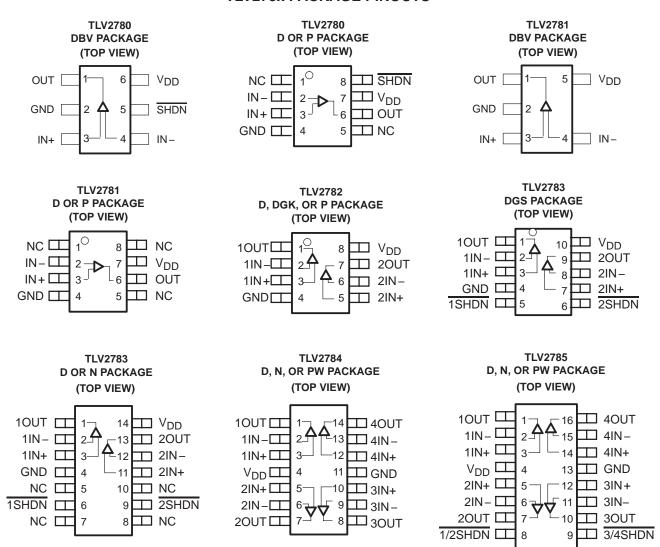


[‡] This package is only available taped and reeled. For standard quantities (3,000 pieces per reel), add an **R** suffix (i.e., TLV2780CDBVR). For smaller quantities (250 pieces per mini-reel), add a **T** suffix to the part number (e.g. TLV2780CDBVT).

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TLV278x PACKAGE PINOUTS



NC - No internal connection

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{DD} (see Note 1)		4 V
Differential input voltage, V _{ID}		±V _{DD}
Input current, I _I (any input)		± 10 mA
Output current, IO		± 10 mA
Continuous total power dissipation		See Dissipation Rating Table
Operating free-air temperature range, T _A :	C-suffix	0°C to 70°C
	I-suffix	40°C to 125°C
Maximum junction temperature, T _J		150°C
Storage temperature range, T _{stg}		65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from	case for 10 seconds	260°C

NOTE 1: All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	(∘C/M) ⊝JC	[⊝] JA (°C/W)	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ Power rating	T _A = 125°C POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.3	1022 mW	204.4 mW
D (16)	25.7	114.7	1090 mW	218 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DBV (6)	55	294.3	425 mW	85 mW
DGK (8)	54.2	259.9	481 mW	96.2 mW
DGS (10)	54.1	257.7	485 mW	97 mW
N (14, 16)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW
PW (16)	28.7	161.4	774 mW	154.9 mW

recommended operating conditions

				MIN	MAX	UNIT
Overal continue V	Single supply			1.8	3.6	.,
Supply voltage, V _{DD}	Split s	upply		±0.9	±1.8	V
Common-mode input voltage range, VICR				-0.2	V _{DD} +0.2	V
	C-suffix			0	70	°C
Operating free-air temperature, T _A	I-suffix	I-suffix			125	-0
	.,	V _{DD} < 2.7 V		0.75V _{DD}		
Shutdown on/off voltage level‡	VIH	$V_{DD} = 2.7 \text{ to } 3.6 \text{ V}$		2		V
	VIL				0.6	

[‡] Relative to GND.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted)

dc performance

	PARAMETER	TEST CO	NDITIONS	T _A †	MIN	TYP	MAX	UNIT
			TI \ /070;	25°C		250	3000	
	land effect with me		TLV278x	Full range			4500	l l
VIO	Input offset voltage	$V_O = V_{DD}/2$, $R_L = 2 k\Omega$,	TI \ (0.70 A	25°C		250	2000	μV
		$R_S = 50 \Omega$	TLV278xA	Full range			3000	
αΛΙΟ	Temperature coefficient of input offset voltage	0 1				8		μV/°C
		$V_{IC} = 0 \text{ to } V_{DD},$ $R_S = 50 \Omega$	\/ 4.0\/	25°C	50	76		
			$V_{DD} = 1.8 V$	Full range	50			
CMDD			V _{DD} = 2.7 V/ 3.6 V	25°C	55	80		40
CMRR	Common-mode rejection ratio			Full range	50			dB
		$V_{IC} = 1.2 \text{ V to } V_{DD}$	V 07V/26V	25°C	70	100		
		$R_S = 50 \Omega$	$V_{DD} = 2.7 \text{ V/ } 3.6 \text{ V}$	Full range	70			
				25°C	200	600		
١.	Large-signal differential voltage	$R_L = 2 k\Omega$, $V_O(PP) = 1 V$	V _{DD} = 1.8 V	Full range	50			ļ ,,, ,,
AVD	amplification		0.7.1/0.0.1/	25°C	200	1000		V/mV
			$V_{DD} = 2.7 \text{ V/ } 3.6 \text{ V}$	Full range	70			

[†] Full range is 0°C to 70°C for the C-suffix and –40°C to 125°C for the I-suffix. If not specified, full range is –40°C to 125°C.

input characteristics

	PARAMETER	TEST C	ONDITIONS	T _A †	MIN	TYP	MAX	UNIT
I _{IO} Input offset current				25°C		2.5	15	
		TLV278xC	Full range			100	рА	
		$V_O = V_{DD}/2,$ $R_L = 2 k\Omega,$	TLV278xI	Full range			300	
		$R_{S} = 50 \Omega$		25°C		2.5	15	
I _{IB}	Input bias current	11.5 - 00 22	TLV278xC	Full range			100	pА
			TLV278xI	Full range			300	
r _{i(d)}	Differential input resistance			25°C		1000		GΩ
C _{i(c)}	Common-mode input capacitance	f = 1 kHz		25°C		19		pF

[†] Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.



TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted) (continued)

output characteristics

	PARAMETER	TEST CON	DITIONS	T _A †	MIN	TYP	MAX	UNIT	
			V 4.0.V	25°C	1.7	1.77			
			$V_{DD} = 1.8 V$	Full range	1.63				
		$I_{OH} = -1 \text{ mA}$	V 07V	25°C	2.6	2.68			
			$V_{DD} = 2.7 V$	Full range	2.6				
\/ - · ·	High lavel autout valence		$V_{DD} = 3.6 \text{ V}$	25°C		3.58			
VOH	High-level output voltage		V 4.9.V	25°C	1.5	1.55		V	
			$V_{DD} = 1.8 V$	Full range	1.46				
		$I_{OH} = -5 \text{ mA}$	\/ 07\/	25°C	2.5	2.55			
			$V_{DD} = 2.7 V$	Full range	2.45				
			$V_{DD} = 3.6 \text{ V}$	25°C		3.55			
		I _{OL} = 1 mA		25°C			70		
				Full range			80		
\/~.	Low-level output voltage		V _{DD} = 1.8 V	25°C		180	240	mV	
VOL	Low-level output voltage	I _{OL} = 5 mA	vDD = 1.6 v	Full range			290		
			\/== - 2.7.\/	25°C		120	170		
			$V_{DD} = 2.7 V$	Full range			200		
		V _{DD} = 1.8 V,	Positive rail			10			
	Output ourrent	VO = 0.5 V from	Negative rail	25°C		15		A	
lO	Output current	$V_{DD} = 2.7 V,$	Positive rail	25°C		17		mA	
		VO = 0.5 V from	Negative rail			23			
		Coursing	$V_{DD} = 1.8 \text{ V}$			13			
loo	Short-circuit output current	Sourcing	$V_{DD} = 2.7 V$	25°C		35		A	
los	Short-orcuit output current	Sinking	$V_{DD} = 1.8 \text{ V}$	25 0		21		mA	
		Sirikiriy	$V_{DD} = 2.7 V$			45			

[†] Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.

power supply

PARAMETER		TEST COND	TEST CONDITIONS			TYP	MAX	UNIT
	Owner to a support (a see also a sell)	V V /0	CUDN V	25°C		650	770	
IDD	Supply current (per channel)	$V_O = V_{DD}/2,$	SHDN = V _{DD}	Full range			820	μΑ
	$V_{DD} = 1.8 \text{ V to } 2.7 \text{ V},$	No load,	25°C	60	75			
		$V_{IC} = V_{DD}/2$		Full range	58			
	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V},$	No load,	25°C	75	90		-ID
ksvr	$(\Delta V_{DD} / \Delta V_{IO})$	$V_{IC} = V_{DD}/2$		Full range	70			dB
		$V_{DD} = 1.8 \text{ V to } 3.6 \text{ V},$	No load,	25°C	65	80		
		$V_{IC} = V_{DD}/2$		Full range	60			

[†] Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.



TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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electrical characteristics at specified free-air temperature, V_{DD} = 1.8 V, 2.7 V (unless otherwise noted) (continued)

dynamic performance

	PARAMETER	TEST CONDIT	TONS	T _A †	MIN	TYP	MAX	UNIT	
UGBW	Unity gain bandwidth	$R_L = 2 k\Omega$,	C _L = 25 pF	25°C		8		MHz	
			V 40V	25°C	3.3	4.3			
			$V_{DD} = 1.8 V$	Full range	3.1				
SR+	Desitive elevante et unity sein	$V_{O(PP)} = 1 \text{ V},$ $R_{L} = 2 \text{ k}\Omega,$	V 27V	25°C	3.8	4.8			
SK+	Positive slew rate at unity gain	$C_L = 50 \text{ pF}$	$V_{DD} = 2.7 V$	Full range	3.5				
			V _{DD} = 3.6 V	25°C	4	5			
				Full range	3.6			1////	
			V 19V	25°C	2.1	2.8		V/μs	
		$V_{O(PP)} = 1 \text{ V},$ $R_{L} = 2 \text{ k}\Omega,$ $C_{L} = 50 \text{ pF}$	$V_{DD} = 1.8 V$	Full range	1.89				
SR-	Negative slew rate at unity gain		V _{DD} = 2.7 V	25°C	2.2	2.8			
SK-	Negative siew rate at unity gain			Full range	1.97				
			V _{DD} = 3.6 V	25°C	3.5	4.2			
			VDD = 3.6 V	Full range	3.4				
φm	Phase margin	$R_L = 2 k\Omega$	C _L = 25 pF	25°C		58°			
	Gain margin	= 2 KS2,	CL = 23 pr	25 0		8		dB	
		V _{DD} = 1.8 V, V(STEP)PP = 1 V,	0.1%			1.7			
	Sattling time	AV = -1, $C_L = 10 \text{ pF}$, $R_L = 2 \text{ k}\Omega$	0.01%	25°C		2.8		116	
t _S	Settling time	V _{DD} = 2.7 V, V(STEP)PP = 1 V,	0.1%	250		1.7		μs	
		AV = -1, $CL = 10 \text{ pF}$, $RL = 2 \text{ k}\Omega$	0.01%			2.4			

[†] Full range is 0°C to 70°C for the C-suffix and –40°C to 125°C for the I-suffix. If not specified, full range is –40°C to 125°C.

noise/distortion performance

	PARAMETER	TEST CONDITI	TEST CONDITIONS			TYP	MAX	UNIT
		$V_{O(PP)} = V_{DD}/2,$	A _V = 1			0.055%		
THD + N	Total harmonic distortion plus noise	$R_L = 2 k\Omega$,	$A_{V} = 10$		0.08%			
		f = 10 kHz	$A_V = 100$	0500		0.45%		
V	Emphysical transfer and the second	f = 1 kHz	25°C		18		nV/√ Hz	
V _n	Equivalent input noise voltage	f = 10 kHz				9		nv/√Hz
In	Equivalent input noise current	f = 1 kHz				0.9		fA/√ Hz

shutdown characteristics

	PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
1	Supply current, per channel in shutdown mode	SHDN = 0 V	25°C		900	1400	^
IDD(SHDN)	(TLV2780, TLV2783, TLV2785)	SHDIN = 0 V	Full range			1700	nA
t(on)	Amplifier turnon time‡	$R_L = 2 k\Omega$	0500		800	·	
t(off)	Amplifier turnoff time [‡]	$R_L = 2 k\Omega$	25°C		200		ns

[†] Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.



Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SLOS245E - MARCH 2000 - REVISED JANUARY 2005

TYPICAL CHARACTERISTICS

Table of Graphs

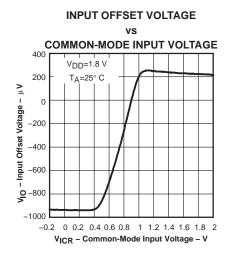
			FIGURE
V _{IO}	Input offset voltage	vs Common-mode input voltage	1, 2
CMRR	Common-mode rejection ratio	vs Frequency	3
VOH	High-level output voltage	vs High-level output current	4, 6
V _{OL}	Low-level output voltage	vs Low-level output current	5, 7
V _{O(PP)}	Maximum peak-to-peak output voltage	vs Frequency	8
Z _O	Output impedance	vs Frequency	9
I _{DD}	Supply current	vs Supply voltage	10
I_{DD}	Supply current	vs Free-air temperature	11
PSRR	Power supply rejection ratio	vs Frequency	12
AVD	Differential voltage amplification & phase	vs Frequency	13
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TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE



COMMON-MODE INPUT VOLTAGE 100 V_{DD}=2.7 V 50 T_A=25 °C ₹. C Voltage -50 -100 - Input Offset -150 -200 -250 -300 -350 0.6 1 1.4 1.8 2.2 V_{ICR} - Common-Mode Input Voltage - V

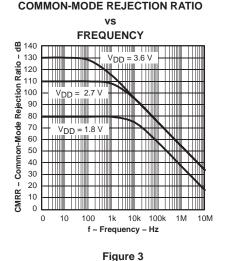


Figure 1 HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT 1.8 V_{DD}=1.8 V 1.6 - High-Level Output Voltage - V 1.2 T_A = 125°C 1.0 = 70°C 0.8 T_A = 25°C 0.6 $T_A = 0^{\circ}C$ $T_A = -40^{\circ}C$ 0.4 8 0.2 0.0 6 8 10 12 IOH - High-Level Output Current - mA

Figure 4

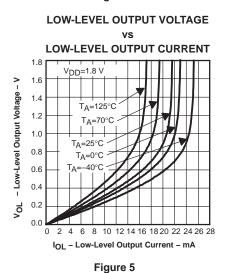
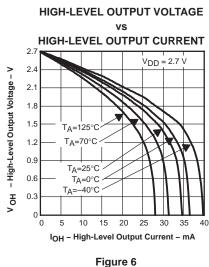
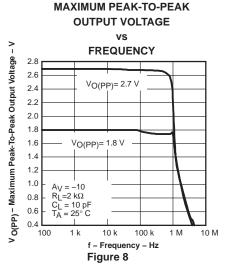
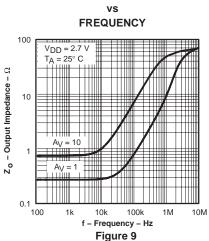


Figure 2



LOW-LEVEL OUTPUT VOLTAGE VS LOW-LEVEL OUTPUT CURRENT 2.7 Low-Level Output Voltage – V 2.4 2.1 T_A=125°C 1.8 T_A= 70°C T_A=25°C 1.5 T_A=0°C 1.2 Γ_Δ=-40°C 0.9 0.6 0.0 10 15 20 25 30 35 40 45 50 55 IOL - Low-Level Output Current - mA Figure 7



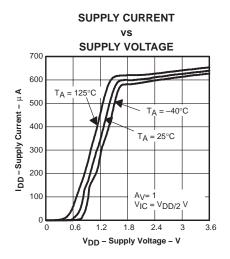


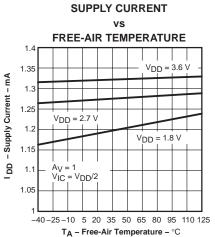
OUTPUT IMPEDANCE

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TYPICAL CHARACTERISTICS





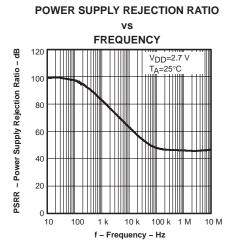
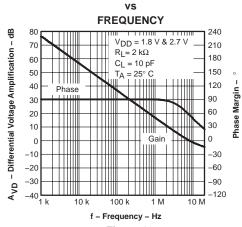


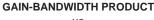
Figure 10

Figure 11

Figure 12

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE





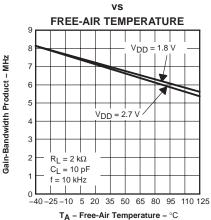
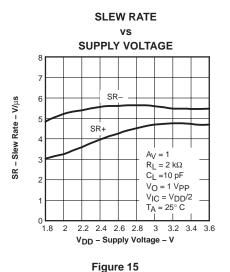
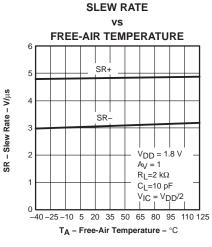


Figure 13

Figure 14





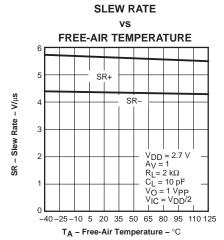


Figure 16

Figure 17



TYPICAL CHARACTERISTICS

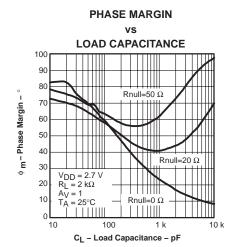


Figure 18

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

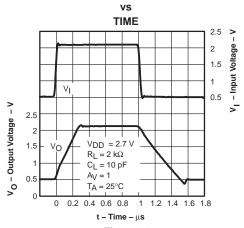


Figure 20

INVERTING LARGE-SIGNAL PULSE RESPONSE

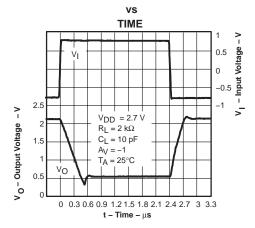


Figure 22

EQUIVALENT INPUT NOISE VOLTAGE

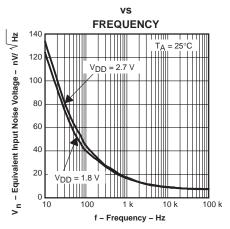


Figure 19

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

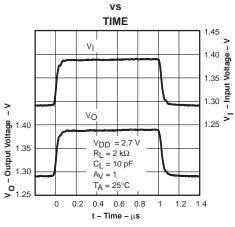


Figure 21

INVERTING SMALL-SIGNAL PULSE RESPONSE

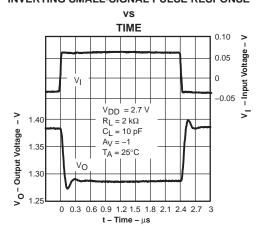


Figure 23

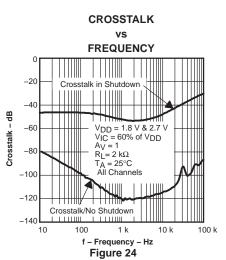


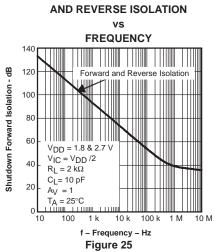
TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

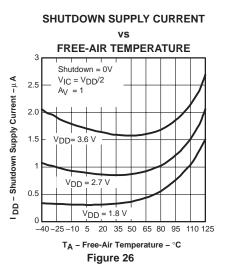
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TYPICAL CHARACTERISTICS

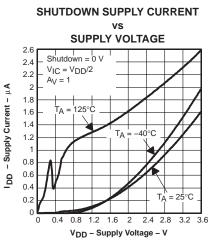
SHUTDOWN FORWARD



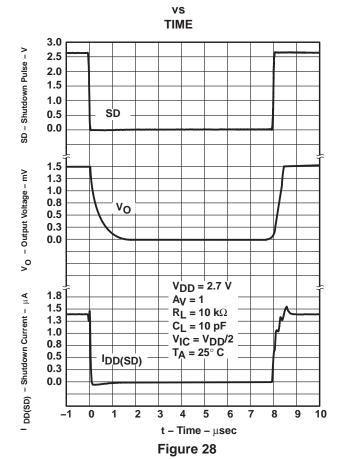




SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE







TEXAS INSTRUMENTS

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PARAMETER MEASUREMENT INFORMATION

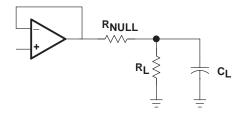


Figure 29

APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 30.

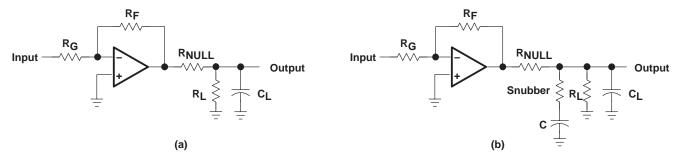


Figure 30. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

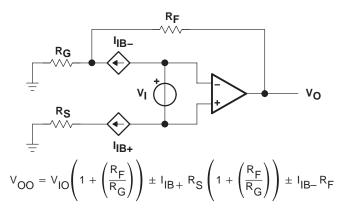


Figure 31. Output Offset Voltage Model



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APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 32).

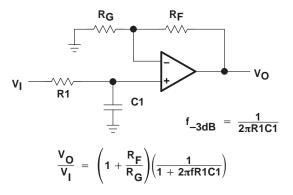


Figure 32. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

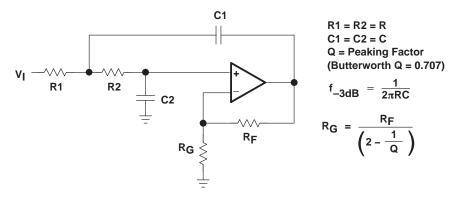


Figure 33. 2-Pole Low-Pass Sallen-Key Filter

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APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV278x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes It is highly recommended that a ground plane be used on the board to provide all
 components with a low inductive ground connection. However, in the areas of the amplifier inputs and
 output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets Sockets can be used but are not recommended. The additional lead inductance in the socket pins
 will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board
 is the best implementation.
- Short trace runs/compact part placements Optimum high performance is achieved when stray series
 inductance has been minimized. To realize this, the circuit layout should be made as compact as possible,
 thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of
 the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at
 the input of the amplifier.
- Surface-mount passive components Using surface-mount passive components is recommended for high
 performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of
 surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small
 size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray
 inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be
 kept as short as possible.

shutdown function

Three members of the TLV278x family (TLV2780/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 900 nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.



TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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APPLICATION INFORMATION

general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 34 and is calculated by the following formula:

$$\mathsf{P}_\mathsf{D} = \left(\frac{\mathsf{T}_\mathsf{MAX}^{-\mathsf{T}}\mathsf{A}}{\theta_\mathsf{JA}}\right)$$

Where:

P_D = Maximum power dissipation of TLV278x IC (watts)

T_{MAX} = Absolute maximum junction temperature (150°C)

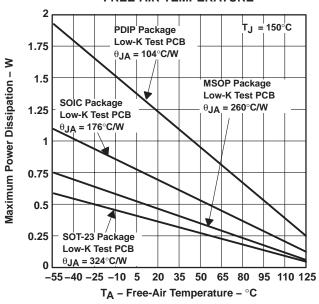
 T_A = Free-ambient air temperature (°C)

 $\theta_{JA} = \theta_{JC} + \theta_{CA}$

 θ_{JC} = Thermal coefficient from junction to case

 θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

MAXIMUM POWER DISSIPATION vs FREE-AIR TEMPERATURE



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 34. Maximum Power Dissipation vs Free-Air Temperature



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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim $Parts^{TM}$ Release 9.1, the model generation software used with Microsim $PSpice^{TM}$. The Boyle macromodel (see Note 2) and subcircuit in Figure 35 are generated using TLV278x typical electrical and operating characteristics at $T_A = 25^{\circ}$ C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 2: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

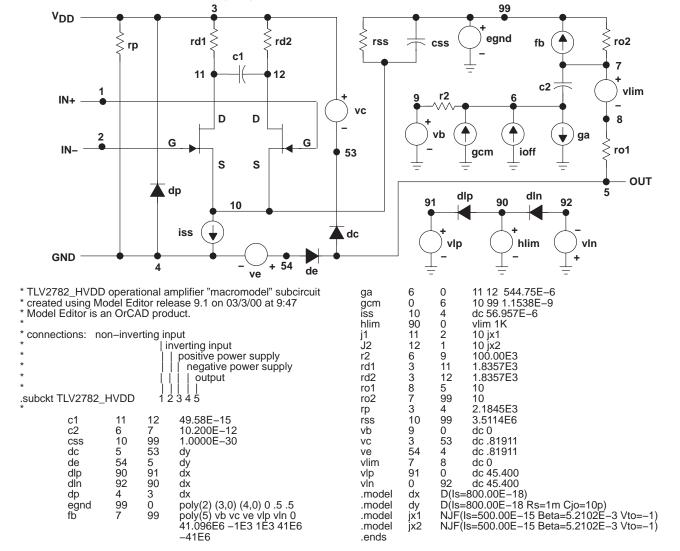


Figure 35. Boyle Macromodel and Subcircuit

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2780CDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VASC	Samples
TLV2780CDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	PDAU Level-1-260C-UNLIM 0		VASC	Samples
TLV2780CDBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VASC	Samples
TLV2780IDBVR	VR ACTIVE SOT-23 DBV 6 3000 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -40 to 125 & no Sb/Br)		-40 to 125	VASI	Samples						
TLV2780IDBVT	VT ACTIVE SOT-23 DBV 6 250 Green (RoHS CU NIPDAU Level-1-260C-UNLIM -40 to 125 & no Sb/Br)		-40 to 125	VASI	Samples						
TLV2780IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2780I	Samples
TLV2781CDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781CDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781CDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	VATC	Samples
TLV2781ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2781IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VATI	Samples
TLV2781IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2781IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	T2781I	Samples
TLV2782AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2782AI	Samples
TLV2782CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Samples



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2782CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Sample
TLV2782CDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADL	Sample
TLV2782CDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADL	Sample
TLV2782CDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ADL	Samples
TLV2782CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2782C	Samples
TLV2782ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27821	Samples
TLV2782IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ADM	Samples
TLV2782IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ADM	Samples
TLV2782IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27821	Samples
TLV2782IP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2782IP	Samples
TLV2783IDGS	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IDGSG4	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ADO	Samples
TLV2783IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2783I	Samples
TLV2784AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784AI	Samples
TLV2784AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2784AI	Samples
TLV2784CPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2784C	Samples
TLV2784ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2784I	Samples



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PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TLV2784IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2784I	Samples
TLV2784IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27841	Samples
TLV2784IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27841	Samples
TLV2785AID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2785AI	Samples
TLV2785CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2785C	Samples
TLV2785IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2785I	Samples
TLV2785INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	TLV2785I	Samples
TLV2785IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27851	Samples
TLV2785IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	27851	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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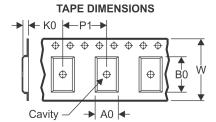
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



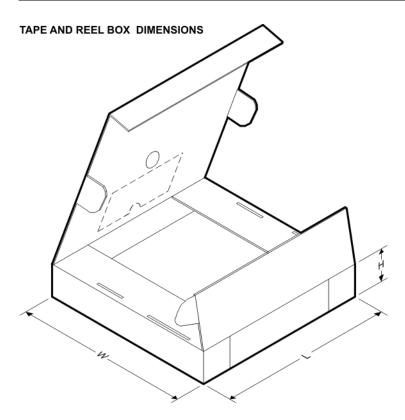
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter		A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
					(mm)	W1 (mm)						
TLV2780CDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780CDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2780IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2781CDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781CDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2781IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2782CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2782IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2782IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2783IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2784AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2784CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2784IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2784IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2785CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2785IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2780CDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2780CDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2780IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2780IDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2780IDR	SOIC	D	8	2500	367.0	367.0	38.0
TLV2781CDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2781CDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2781IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2781IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2781IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2782CDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2782CDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0



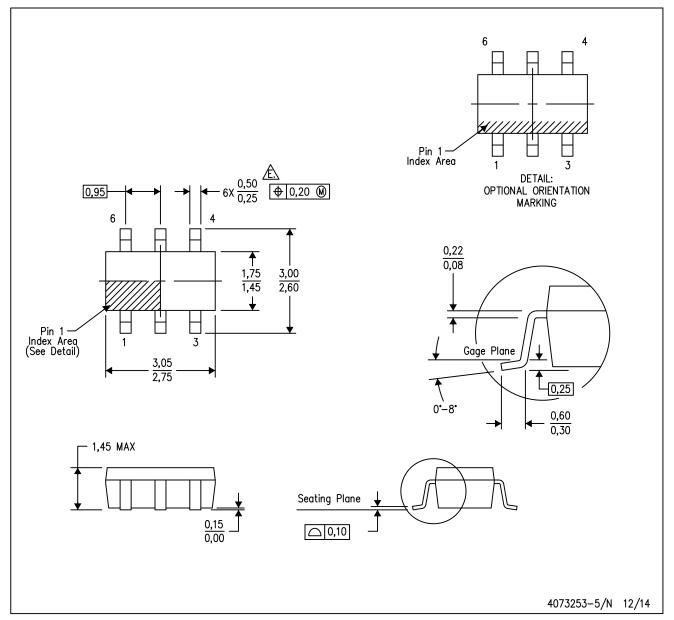
PACKAGE MATERIALS INFORMATION

www.ti.com 24-Aug-2017

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2782CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2782IDGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TLV2782IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2782IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2783IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2784AIDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2784CPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2784IDR	SOIC	D	14	2500	367.0	367.0	38.0
TLV2784IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TLV2785CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TLV2785IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE

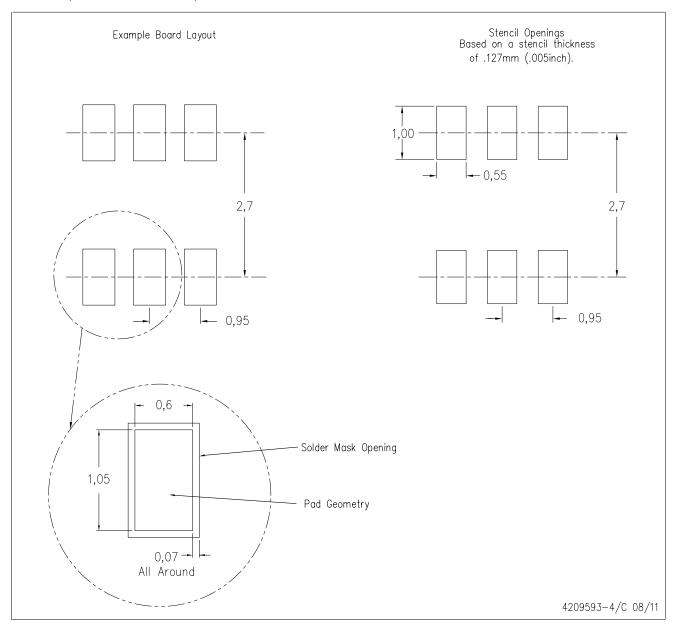


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE

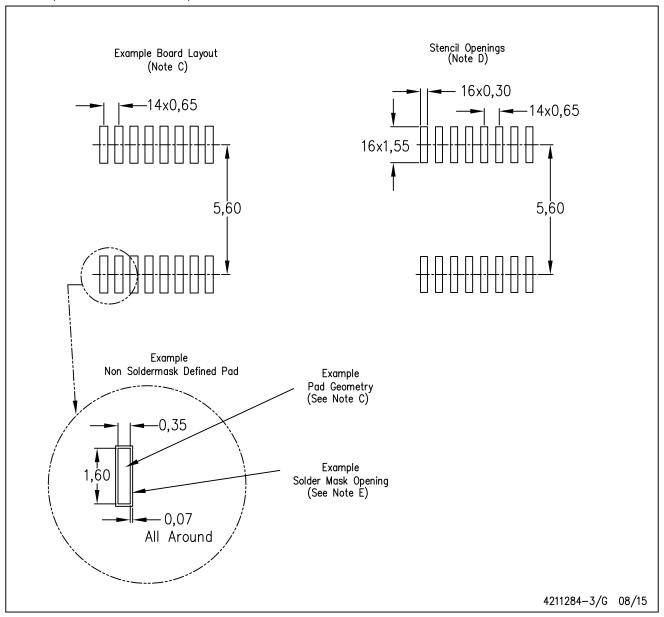


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

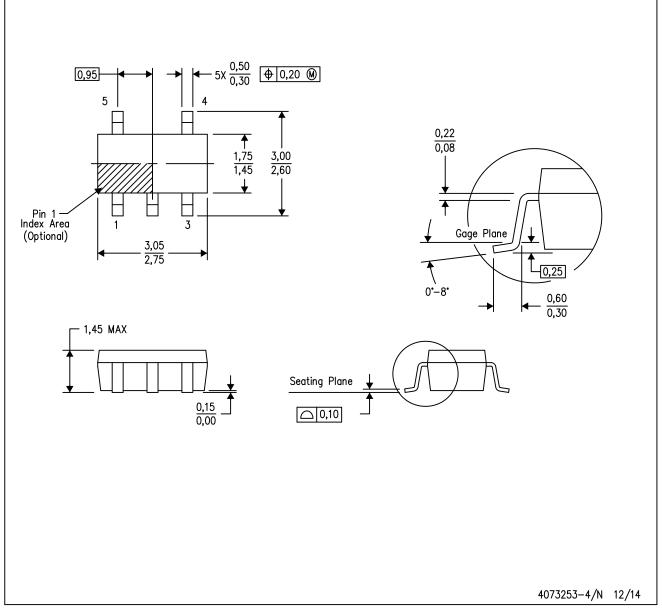


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.



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